

N-Channel Super Junction Power MOSFET IV

General Description

The series of devices use advanced trench gate super junction technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

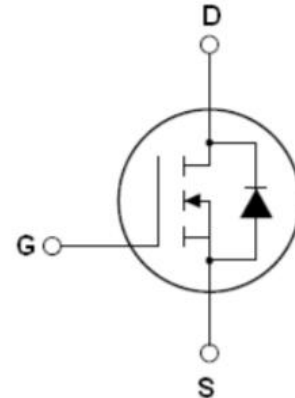
Features

- New technology for high voltage device
- Low on-resistance and low conduction losses
- Small package
- Ultra Low Gate Charge cause lower driving requirements
- 100% Avalanche Tested
- ROHS compliant

Application

- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)

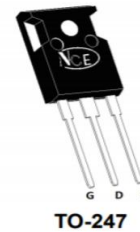
| | | |
|------------------------|-----|------------|
| $V_{DS\ min@T_{jmax}}$ | 710 | V |
| $R_{DS(ON)TYP.}$ | 30 | m Ω |
| I_D | 70 | A |
| Q_g | 102 | nC |



Schematic diagram

Package Marking And Ordering Information

| Device | Device Package | Marking |
|-------------|----------------|-------------|
| NCE65NF036T | TO-247 | NCE65NF036T |



TO-247

Table 1. Absolute Maximum Ratings ($T_c=25^\circ\text{C}$)

| Parameter | Symbol | Value | Unit |
|--|------------------|------------|---------------------|
| Drain-Source Voltage ($V_{GS}=0V$) | V_{DS} | 650 | V |
| Gate-Source Voltage ($V_{DS}=0V$), AC ($f>1\text{ Hz}$) | V_{GS} | ± 30 | V |
| Continuous Drain Current at $T_c=25^\circ\text{C}$ | $I_{D(DC)}$ | 70 | A |
| Continuous Drain Current at $T_c=100^\circ\text{C}$ | $I_{D(DC)}$ | 49 | A |
| Pulsed drain current (Note 1) | I_{DM} (pluse) | 210 | A |
| Maximum Power Dissipation($T_c=25^\circ\text{C}$) | P_D | 488 | W |
| Derate above 25°C | | 3.25 | W/ $^\circ\text{C}$ |
| Single pulse avalanche energy (Note 2) | E_{AS} | 2117 | mJ |
| Single pulse avalanche current (Note 2) | I_{AS} | 11 | A |
| Repetitive Avalanche energy, t_{AR} limited by T_{jmax} (Note 1) | E_{AR} | 0.9 | mJ |
| Reverse diode dv/dt, $V_{DS} \leq 480\text{ V}, I_{SD} < I_D$ | dv/dt | 50 | V/ns |
| Drain Source voltage slope, $V_{DS} \leq 480\text{ V}$ | dv/dt | 50 | V/ns |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55...+175 | $^\circ\text{C}$ |

Table 2. Thermal Characteristic

| Parameter | Symbol | Value | Unit |
|---|------------|-------|-----------------------------|
| Thermal Resistance, Junction-to-Case (Maximum) | R_{thJC} | 0.31 | $^{\circ}\text{C}/\text{W}$ |
| Thermal Resistance, Junction-to-Ambient (Maximum) | R_{thJA} | 62 | $^{\circ}\text{C}/\text{W}$ |

Table 3. Electrical Characteristics (TA=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|--|--------------|--|-----|------|-----------|---------------|
| On/off states | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=1mA$ | 650 | | | V |
| Zero Gate Voltage Drain Current($T_c=25^{\circ}\text{C}$) | I_{DSS} | $V_{DS}=650V, V_{GS}=0V$ | | | 10 | μA |
| Zero Gate Voltage Drain Current($T_c=125^{\circ}\text{C}$) | I_{DSS} | $V_{DS}=650V, V_{GS}=0V$ | | | 400 | μA |
| Gate-Body Leakage Current | I_{GSS} | $V_{GS}=\pm 20V, V_{DS}=0V$ | | | ± 200 | nA |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=3mA$ | 3 | 4 | 5 | V |
| Drain-Source On-State Resistance | $R_{DS(on)}$ | $V_{GS}=10V, I_D=35A$ | | 30 | 36 | m Ω |
| Dynamic Characteristics | | | | | | |
| Gate Resistance | R_g | $F=1\text{MHz}, \text{D-S short}$ | | 4 | | Ω |
| Input Capacitance | C_{iss} | $V_{DS}=50V, V_{GS}=0V,$ $F=1\text{MHz}$ | | 6287 | | pF |
| Output Capacitance | C_{oss} | | | 263 | | pF |
| Reverse Transfer Capacitance | C_{riss} | | | 15.1 | | pF |
| Total Gate Charge | Q_g | $V_{DS}=400V, I_D=40A, V_{GS}=10V$ | | 102 | 108 | nC |
| Gate-Source Charge | Q_{gs} | | | 37 | | nC |
| Gate-Drain Charge | Q_{gd} | | | 22 | | nC |
| Gate plateau voltage | V_{gp} | | | 6 | | V |
| Switching times | | | | | | |
| Turn-on Delay Time | $t_{d(on)}$ | $V_{DD}=380V, I_D=40A,$ $R_G=4\Omega, V_{GS}=10V$ | | 54 | | nS |
| Turn-on Rise Time | t_r | | | 37 | | nS |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 127 | | nS |
| Turn-Off Fall Time | t_f | | | 5 | | nS |
| Source- Drain Diode Characteristics | | | | | | |
| Source-drain current(Body Diode) | I_{SD} | $T_c=25^{\circ}\text{C}$ | | | 70 | A |
| Pulsed-Source-drain current(Body Diode) | I_{SDM} | | | | 210 | A |
| Forward on voltage | V_{SD} | $T_j=25^{\circ}\text{C}, I_{SD}=70A, V_{GS}=0V$ | | 1.0 | 1.2 | V |
| Reverse Recovery Time | t_{rr} | $T_j=25^{\circ}\text{C}, I_F=40A,$ $di/dt=100A/\mu\text{s}$ | | 185 | | nS |
| Reverse Recovery Charge | Q_{rr} | | | 1.6 | | μC |
| Peak reverse recovery current | I_{rrm} | | | 16 | | A |

Notes: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

2. $T_j=25^{\circ}\text{C}, V_{DD}=50V, V_G=10V, R_G=25\Omega, L=35\text{mH}$

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

Figure1. Safe operating area

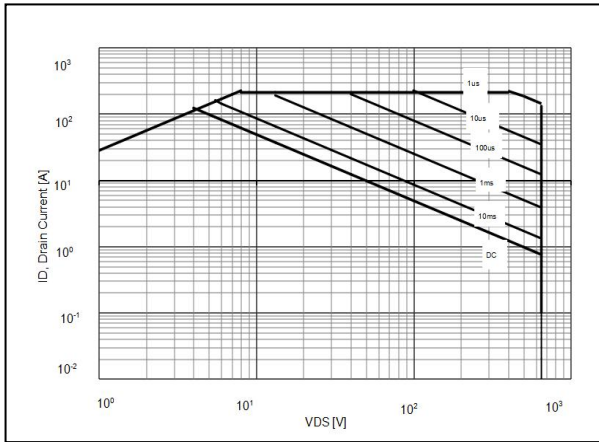


Figure2. Source-Drain Diode Forward Voltage

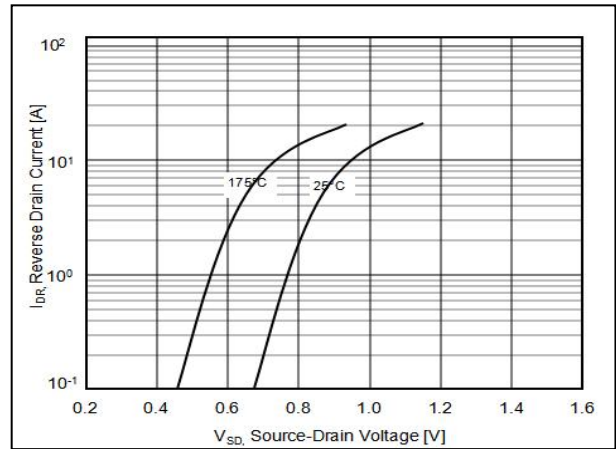


Figure3. Output characteristics (25°C)

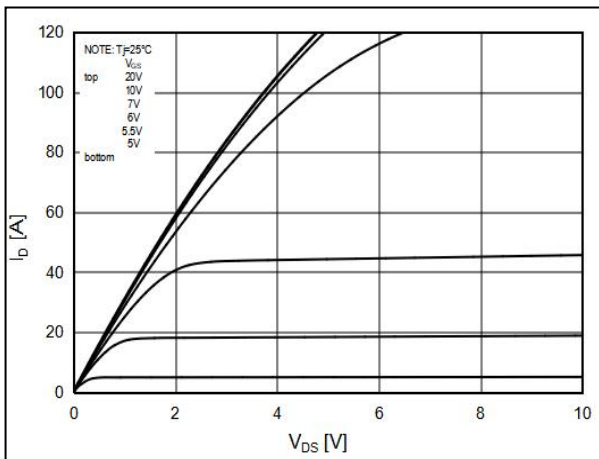


Figure4. Output characteristics (100°C)

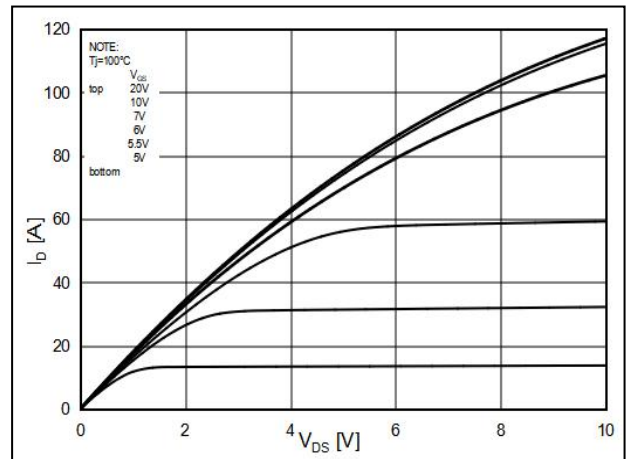


Figure5. Transfer characteristics

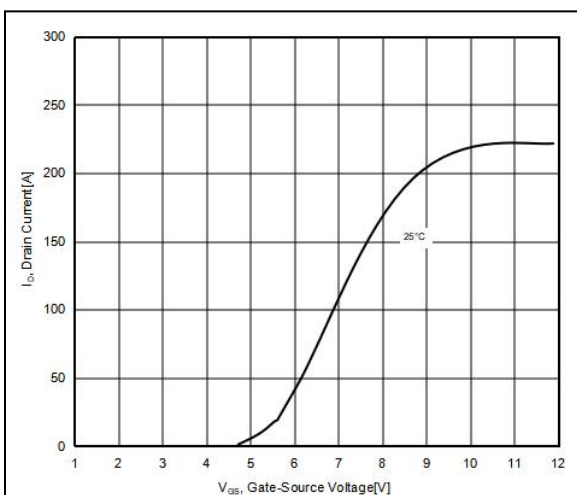


Figure6. Static drain-source on resistance

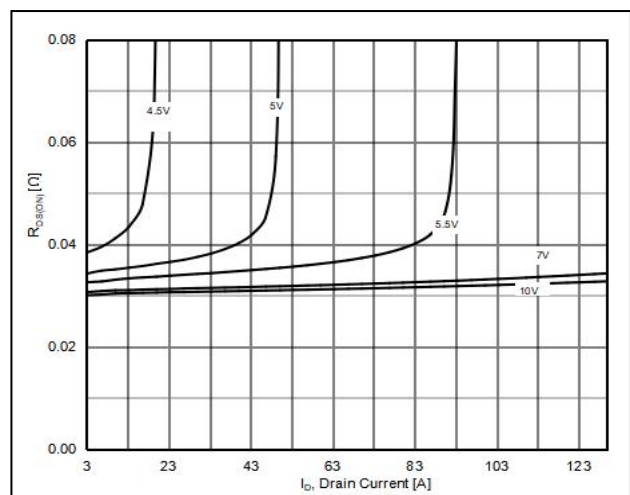


Figure7. $R_{DS(ON)}$ vs Junction Temperature

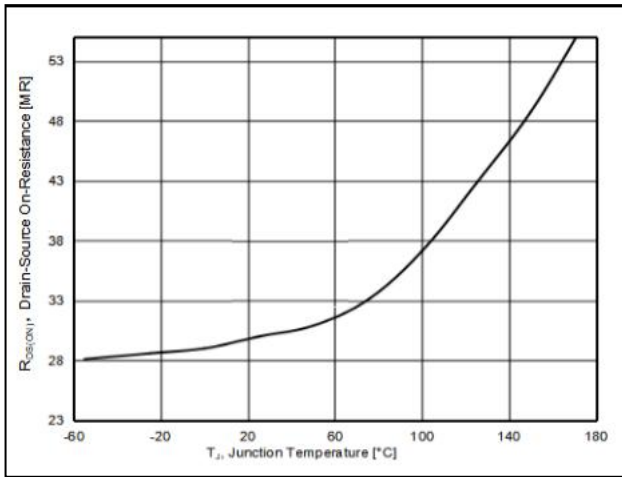


Figure8. BV_{DSS} vs Junction Temperature

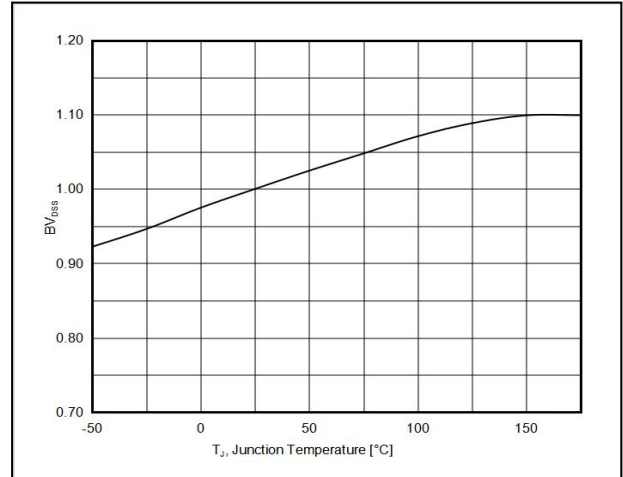


Figure9. Maximum I_D vs Junction Temperature

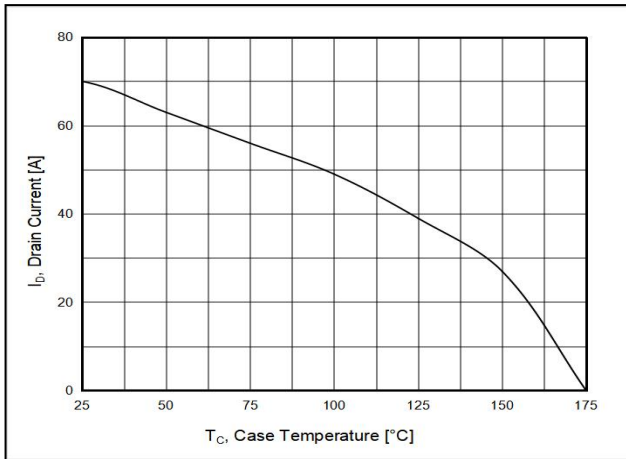


Figure10. Gate charge waveforms

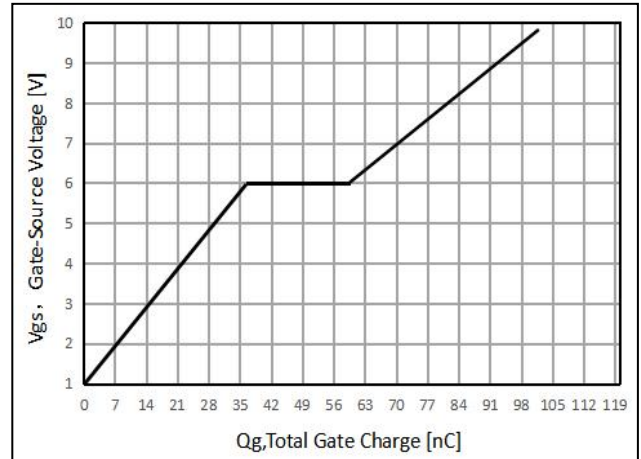
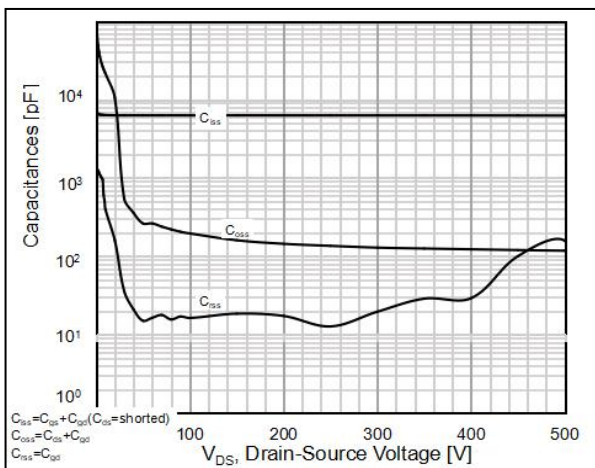
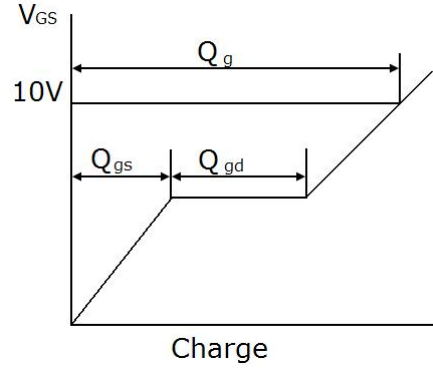
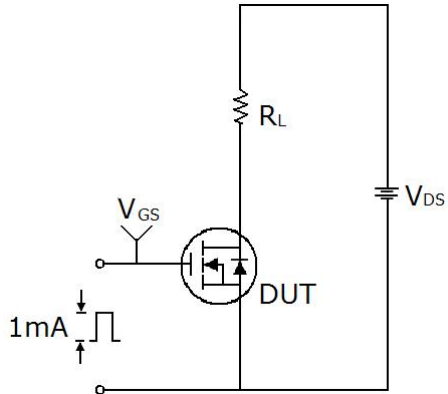


Figure11. Capacitance

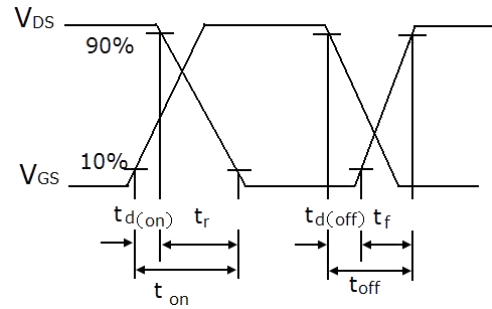
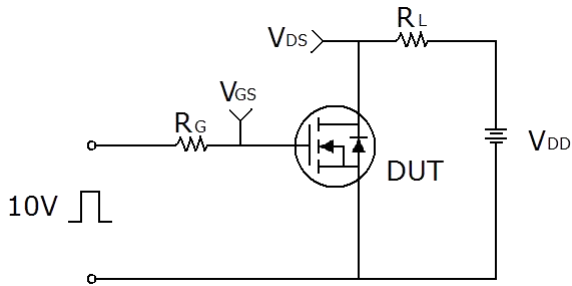


Test circuit

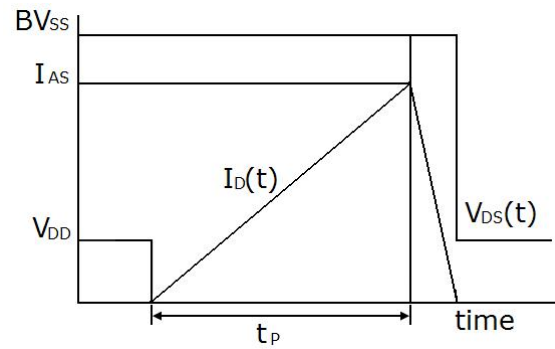
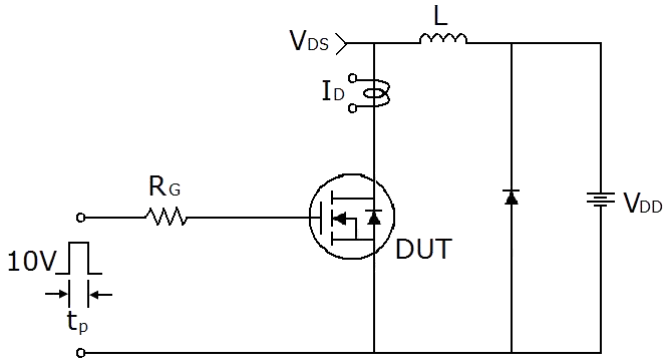
1) Gate charge test circuit & Waveform



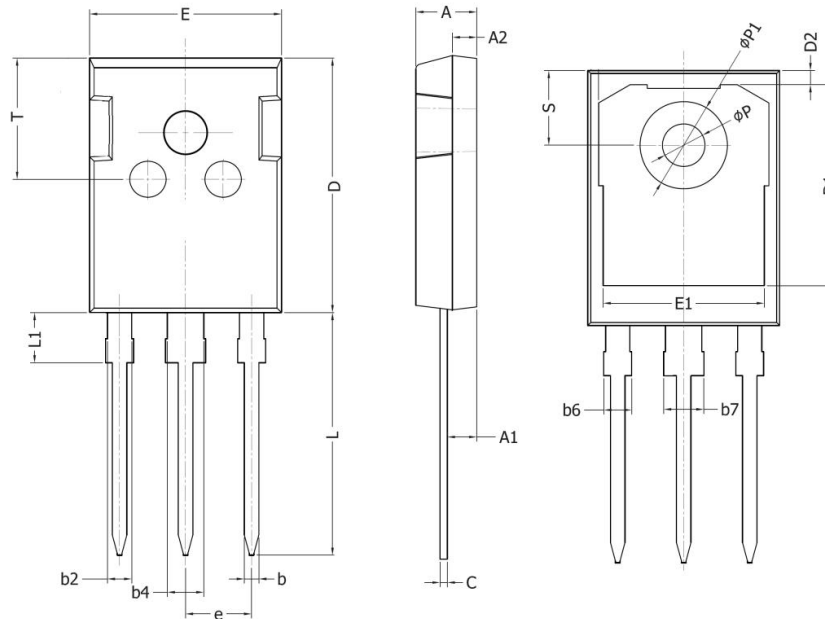
2) Switch Time Test Circuit:



3) Unclamped Inductive Switching Test Circuit & Waveforms

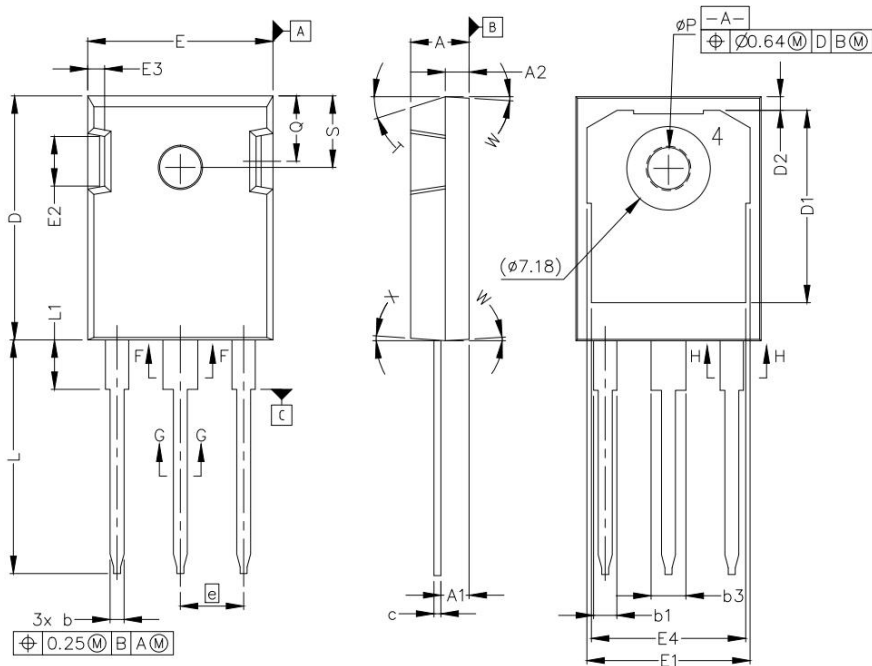


TO-247 (P) Package Information



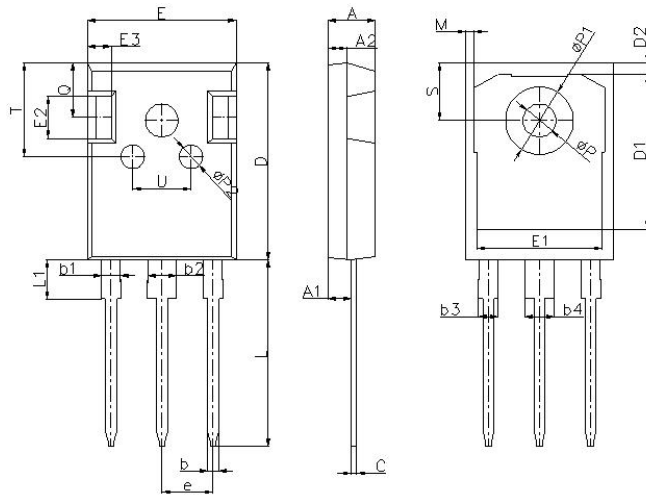
| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.90 | 5.10 | 0.193 | 0.201 |
| A1 | 2.31 | 2.51 | 0.091 | 0.099 |
| A2 | 1.90 | 2.10 | 0.075 | 0.083 |
| b | 1.16 | 1.26 | 0.046 | 0.050 |
| b2 | 1.96 | 2.06 | 0.077 | 0.081 |
| b4 | 2.96 | 3.06 | 0.117 | 0.120 |
| b6 | - | 2.25 | - | 0.089 |
| b7 | - | 3.25 | - | 0.128 |
| C | 0.59 | 0.66 | 0.023 | 0.026 |
| D | 20.90 | 21.10 | 0.823 | 0.831 |
| D1 | 16.25 | 16.85 | 0.640 | 0.663 |
| D2 | 1.05 | 1.35 | 0.041 | 0.053 |
| E | 15.70 | 15.90 | 0.618 | 0.626 |
| E1 | 13.10 | 13.50 | 0.516 | 0.531 |
| e | 5.436 BSC | | 0.214 BSC | |
| L | 19.80 | 20.10 | 0.780 | 0.791 |
| L1 | - | 4.30 | - | 0.169 |
| P | 3.40 | 3.60 | 0.134 | 0.142 |
| P1 | 7.00 | 7.40 | 0.276 | 0.291 |
| S | 6.05 | 6.25 | 0.238 | 0.246 |
| T | 9.80 | 10.20 | 0.386 | 0.402 |

TO-247-B Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.83 | 5.21 | 0.190 | 0.205 |
| A1 | 2.29 | 2.54 | 0.090 | 0.100 |
| A2 | 1.91 | 2.16 | 0.075 | 0.085 |
| b | 1.07 | 1.33 | 0.042 | 0.052 |
| b1 | 1.91 | 2.41 | 0.075 | 0.095 |
| b3 | 2.87 | 3.38 | 0.113 | 0.133 |
| c | 0.55 | 0.68 | 0.022 | 0.027 |
| D | 20.80 | 21.10 | 0.819 | 0.831 |
| D1 | 16.25 | 17.65 | 0.640 | 0.695 |
| D2 | 0.95 | 1.25 | 0.037 | 0.049 |
| E | 15.75 | 16.13 | 0.620 | 0.635 |
| E1 | 13.10 | 14.15 | 0.516 | 0.557 |
| E2 | 3.68 | 5.10 | 0.145 | 0.201 |
| E3 | 1.00 | 1.90 | 0.039 | 0.075 |
| E4 | 12.38 | 13.43 | 0.487 | 0.529 |
| e | 5.44 BSC | | 0.214 BSC | |
| N | 3.00 | | 0.118 | |
| L | 19.81 | 20.32 | 0.780 | 0.800 |
| L1 | 4.10 | 4.40 | 0.161 | 0.173 |
| P | 3.51 | 3.65 | 0.138 | 0.144 |
| Q | 5.49 | 6.00 | 0.216 | 0.236 |
| S | 6.04 | 6.30 | 0.238 | 0.248 |

TO-247-E Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.90 | 5.10 | 0.193 | 0.201 |
| A1 | 2.31 | 2.51 | 0.091 | 0.099 |
| A2 | 1.90 | 2.10 | 0.075 | 0.083 |
| b | 1.16 | 1.26 | 0.046 | 0.050 |
| b1 | 1.96 | 2.06 | 0.077 | 0.081 |
| b2 | 2.96 | 3.06 | 0.117 | 0.120 |
| b3 | - | 2.25 | - | 0.089 |
| b4 | - | 3.25 | - | 0.128 |
| C | 0.59 | 0.66 | 0.023 | 0.026 |
| D | 20.90 | 21.10 | 0.823 | 0.831 |
| D1 | 16.25 | 16.85 | 0.640 | 0.663 |
| D2 | 1.05 | 1.35 | 0.041 | 0.053 |
| E | 15.70 | 15.90 | 0.618 | 0.626 |
| E1 | 13.10 | 13.50 | 0.516 | 0.531 |
| E2 | 4.40 | 4.60 | 0.173 | 0.181 |
| E3 | 2.40 | 2.60 | 0.094 | 0.102 |
| e | 5.436BSC | | 0.214BSC | |
| L | 19.80 | 20.10 | 0.780 | 0.791 |
| L1 | - | 4.30 | - | 0.169 |
| M | 0.35 | 0.95 | 0.014 | 0.037 |
| P | 3.40 | 3.60 | 0.134 | 0.142 |
| P1 | 7.00 | 7.40 | 0.276 | 0.291 |
| P2 | 2.40 | 2.60 | 0.094 | 0.102 |
| Q | 5.60 | 6.00 | 0.220 | 0.236 |
| S | 6.05 | 6.25 | 0.238 | 0.246 |
| T | 9.80 | 10.20 | 0.386 | 0.402 |
| U | 6.00 | 6.40 | 0.236 | 0.252 |

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